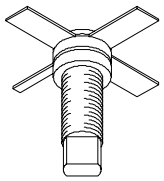
查询MSC80186供应商

SGS-THOMSON MICROELECTRONICS

MSC80186

RF & MICROWAVE TRANSISTORS GENERAL PURPOSE LINEAR APPLICATIONS

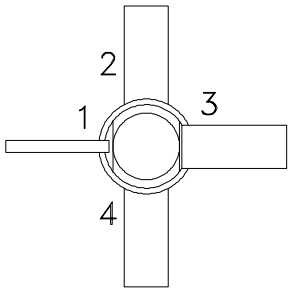
- EMITTER BALLASTED
- CLASS A LINEAR OPERATION
- COMMON EMITTER
- VSWR CAPABILITY 15:1 @ RATED CONDITIONS
- ft 3.2 GHz TYPICAL
- NOISE FIGURE 12.5 dB @ 2 GHz
- P_{OUT} = 30.0 dBm MIN.



.230 4L STUD (S027)
hermetically sealed

ORDER CODE	BRANDING
MSC80186	80186

PIN CONNECTION



1. Collector
2. Emitter
3. Base
4. Emitter

DESCRIPTION

The MSC80185 is a hermetically sealed NPN power transistor featuring a unique matrix structure. This device is specifically designed for Class A linear applications to provide high gain and high output power at the 1.0 dB compression point.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

Symbol	Parameter	Value	Unit
P_{DISS}	Power Dissipation (see Safe Area)	—	W
I_C	Device Bias Current	500	mA
V_{CE}	Collector-Emitter Bias Voltage*	20	V
T_J	Junction Temperature	200	°C
T_{STG}	Storage Temperature	– 65 to +200	°C

THERMAL DATA

$R_{TH(j-c)}$	Junction-Case Thermal Resistance*	17	°C/W

*Applies only to rated RF amplifier operation

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV_{CBO}	I_C = 1mA	I_E = 0mA	50	—	—	V
BV_{EBO}	I_E = 1mA	I_C = 0mA	3.5	—	—	V
BV_{CEO}	IC = 5mA	I_B = 0mA	20	—	—	V
I_{CEO}	V_{CE} = 18V		—	—	1.0	mA
h_{FE}	V_{CE} = 5V	I_C = mA	15	—	120	—

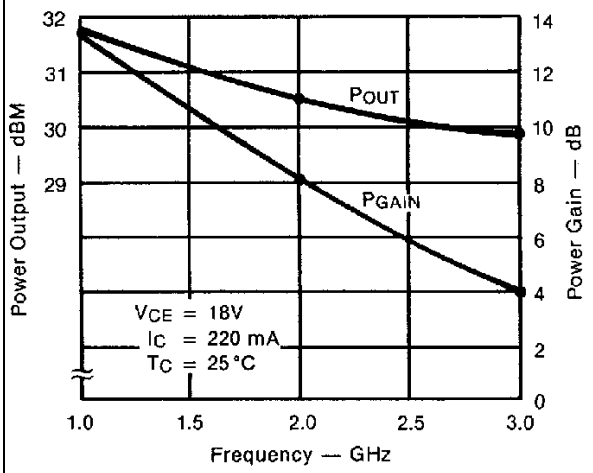
DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
G_P*	f = 2.0 GHz	P_{OUT} = 30.0 dBm		7.0	9.0	—	dB
ΔG_P*	f = 2.0 GHz	P_{OUT} = 30.0 dBm	ΔP_{OUT} = 10 dB	—	—	1	dB
C_{OB}	f = 1 MHz	V_{CB} = 28 V		—	—	5.0	pF

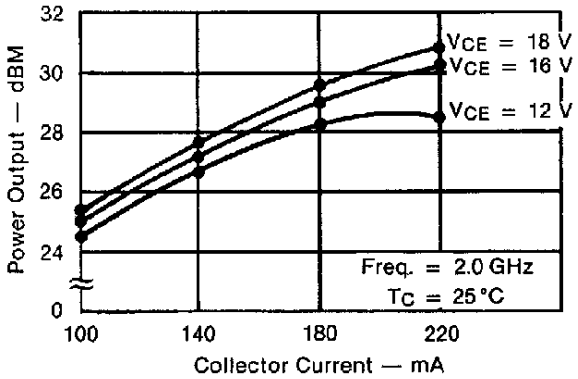
* Note: V_{CE} = 18V
I_C = 220mA

TYPICAL PERFORMANCE

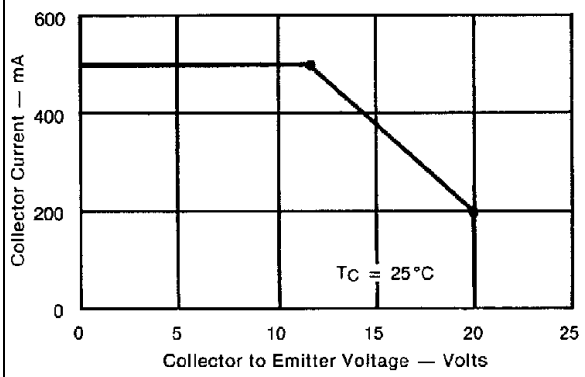
TYPICAL POWER OUTPUT & GAIN @ 1dB COMPRESSION POINT vs FREQUENCY



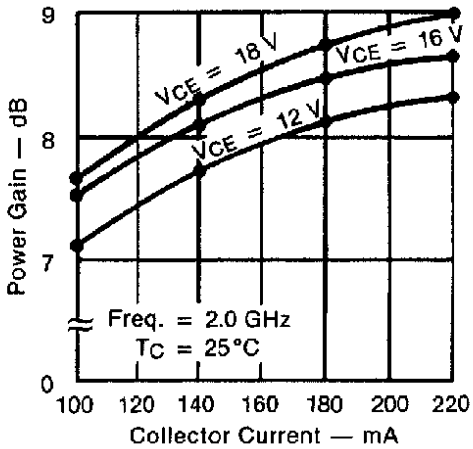
TYPICAL POWER OUTPUT & GAIN @ 1dB COMPRESSION POINT vs COLLECTOR CURRENT



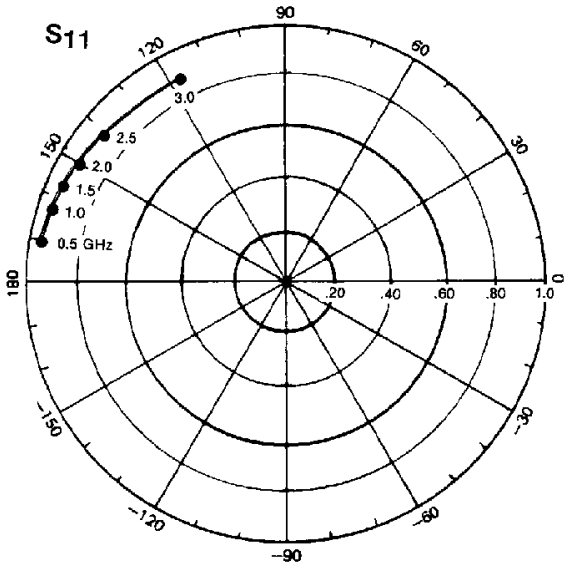
MAXIMUM OPERATING AREA FOR FORWARD BIAS OPERATION

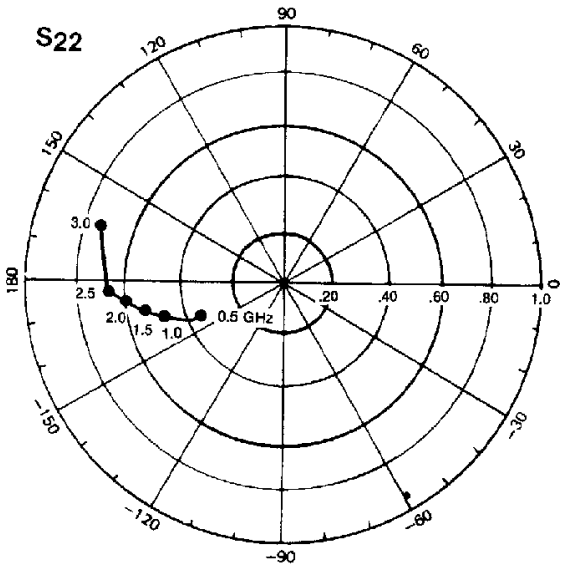


TYPICAL LINEAR GAIN vs COLLECTOR CURRENT

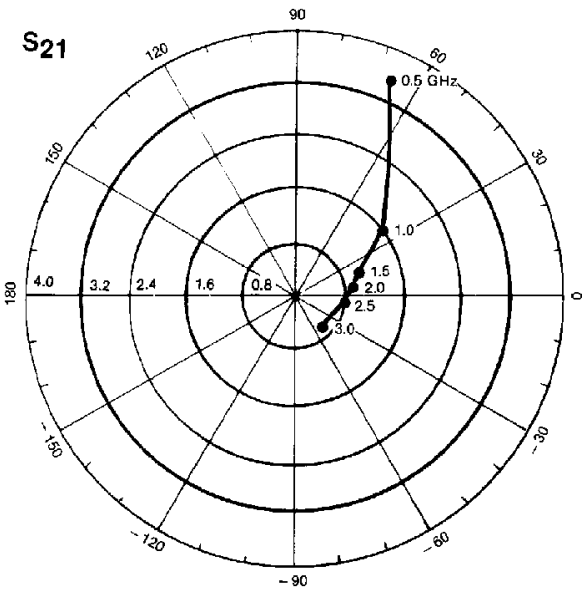


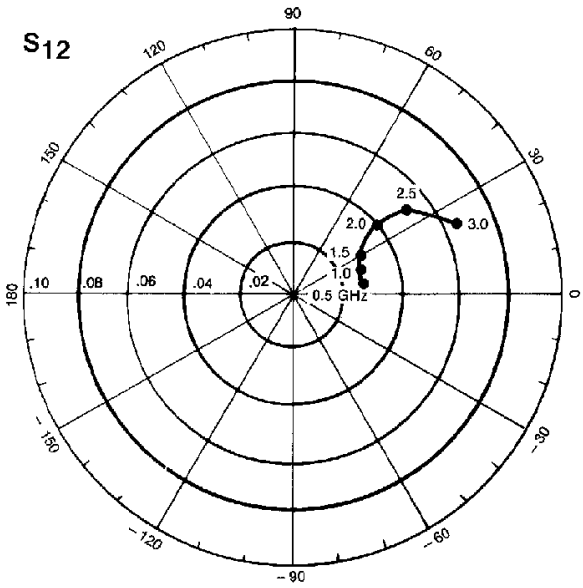
TYPICAL S–PARAMETERS





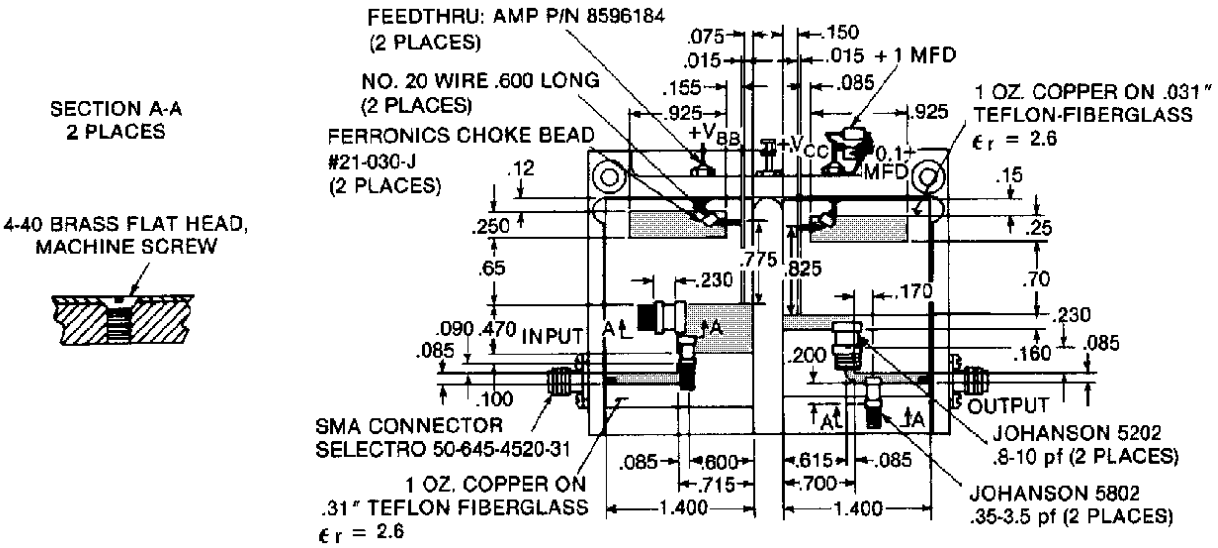
V_{CE} = 18 V
I_C = 220 mA
Zg = 50 ohms





TEST CIRCUIT

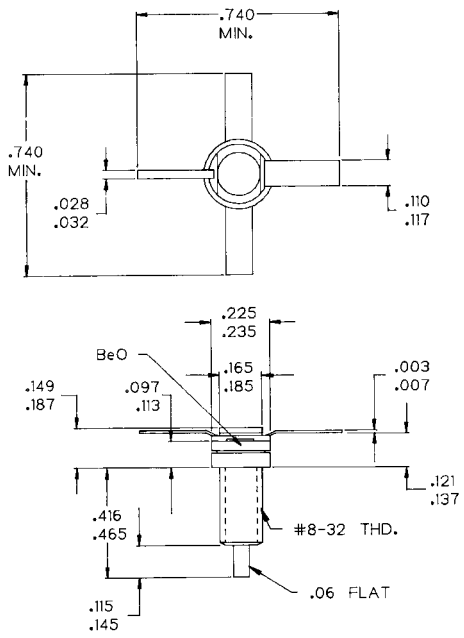
Ref.: Dwg. No. C127305



All dimensions are in inches.

PACKAGE MECHANICAL DATA

Ref.: Dwg. No.: J135023F



NOTES:
1. ALL TOLERANCE ± .010 EXCEPT WHERE NOTED; DIMENSIONS IN INCHES.

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